

FAST RECOVERY DIODES

Hockey Puk Version

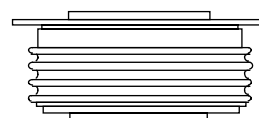
Features

- High power FAST recovery diode series
- 6.0 μ s recovery time
- High voltage ratings up to 4500V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Press-puk encapsulation
- Case style conform to JEDEC DO-200AB (B-PUK)
- Maximum junction temperature 125°C

Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

560A



case style DO-200AB (B-PUK)

Major Ratings and Characteristics

Parameters	SD553C..S50L	Units
$I_{F(AV)}$	560	A
@ T_{hs}	55	°C
$I_{F(RMS)}$	1120	A
@ T_{hs}	25	°C
I_{FSM}	@ 50Hz	12000 A
	@ 60Hz	12570 A
I^2t	@ 50Hz	721 KA ² s
	@ 60Hz	658 KA ² s
V_{RRM} range	3000 to 4500	V
t_{rr}	6.0	μ s
@ T_J	125	°C
T_J	- 40 to 125	°C

SD553C..S50L Series

Bulletin I2092 rev. C 04/00

International
IOR Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

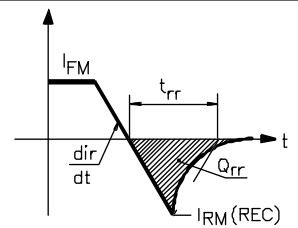
Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = 125^\circ\text{C}$ mA
SD553C..S50L	30	3000	3100	75
	36	3600	3700	
	40	4000	4100	
	45	4500	4600	

Forward Conduction

Parameter	SD553C..S50L	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Heatsink temperature	560 (210)	A	180° conduction, half sine wave
	55 (85)	°C	Double side (single side) cooled
$I_{F(RMS)}$ Max. RMS forward current	1120	A	@ 25°C heatsink temperature double side cooled
I_{FSM} Max. peak, one-cycle forward, non-repetitive surge current	12000	A	t = 10ms No voltage
	12570		t = 8.3ms reapplied
	10100		t = 10ms 50% V_{RRM}
	10570		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing	721	KA ² s	t = 10ms No voltage
	658		t = 8.3ms reapplied
	510		t = 10ms 50% V_{RRM}
	466		t = 8.3ms reapplied
I^2/t Maximum I^2/t for fusing	7210	KA ² /s	t = 0.1 to 10ms, no voltage reapplied
$V_{F(TO)1}$ Low level value of threshold voltage	1.77	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
$V_{F(TO)2}$ High level value of threshold voltage	1.95		$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
r_{f1} Low level value of forward slope resistance	0.98	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
r_{f2} High level value of forward slope resistance	0.89		$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ max.}$
V_{FM} Max. forward voltage drop	3.24	V	$I_{pk} = 1500\text{A}, T_J = 125^\circ\text{C}, t_p = 10\text{ms}$ sinusoidal wave

Recovery Characteristics

Code	$T_J = 25^\circ\text{C}$ Typical t_{rr} @ 25% I_{RRM} (μs)	Test conditions			Max. values @ $T_J = 125^\circ\text{C}$		
		I_{pk} Square Pulse (A)	di/dt (A/μs)	V_r (V)	t_{rr} @ 25% I_{RRM} (μs)	Q_{rr} (μC)	I_{rr} (A)
S50	5.0	1000	100	-50	6.0	900	250



Thermal and Mechanical Specifications

Parameter	SD553C..S50L	Units	Conditions
T _J Max. junction operating temperature range	-40 to 125	°C	
T _{stg} Max. storage temperature range	-40 to 150		
R _{thJ-hs} Max. thermal resistance, junction to heatsink	0.073 0.031	K/W	DC operation single side cooled DC operation double side cooled
F Mounting force, ± 10%	14700 (1500)	N (Kg)	
wt Approximate weight	255	g	
Case style	DO-200AB (B-PUK)		Conforms to JEDEC

ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.009	0.009	0.006	0.006	K/W	T _J = T _J max.
120°	0.011	0.011	0.011	0.011		
90°	0.014	0.014	0.015	0.015		
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

Ordering Information Table

Device Code						
SD	55	3	C	45	S50	L
1	2	3	4	5	6	7
1	- Diode					
2	- Essential part number					
3	- 3 = Fast recovery					
4	- C = Ceramic Puk					
5	- Voltage code: Code x 100 = V _{RRM} (See Voltage Ratings table)					
6	- t _{rr} code					
7	- L = Puk Case DO-200AB (B-PUK)					

SD553C..S50L Series

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Outline Table

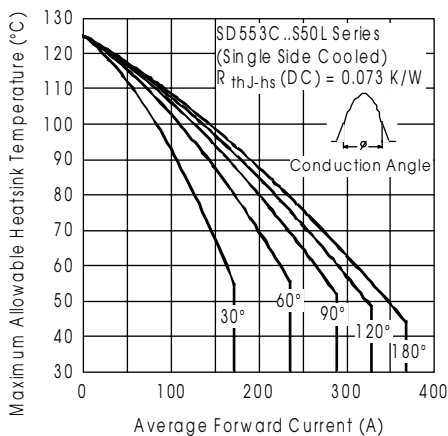
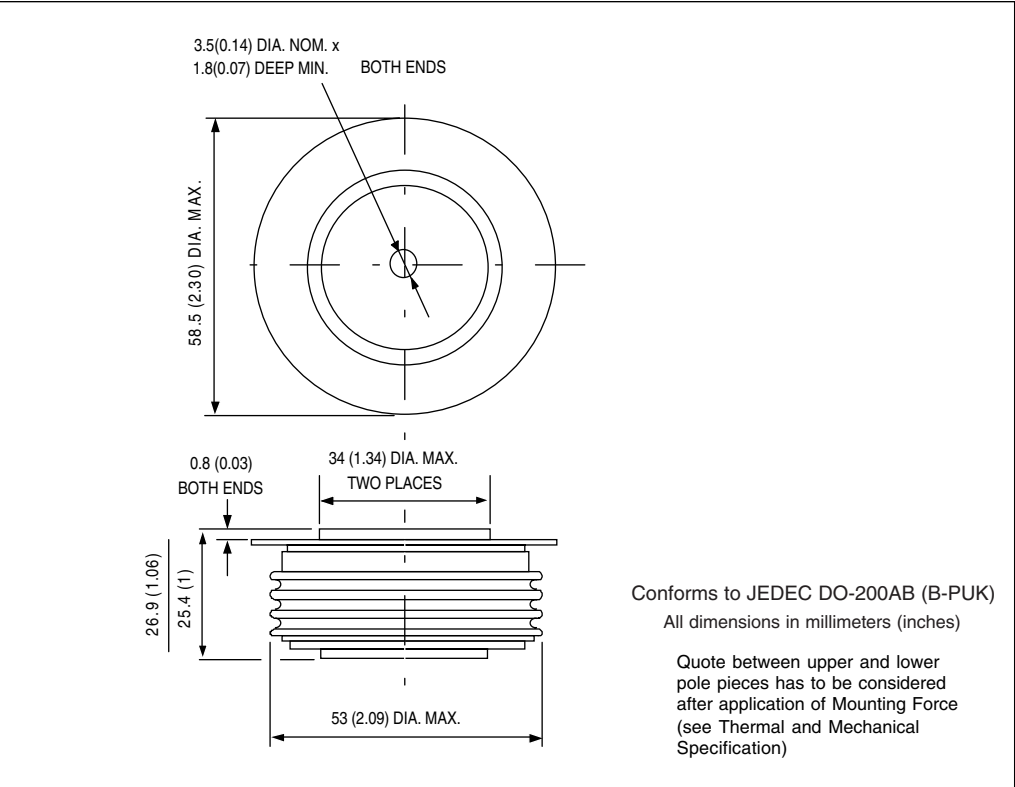


Fig. 1 - Current Ratings Characteristics

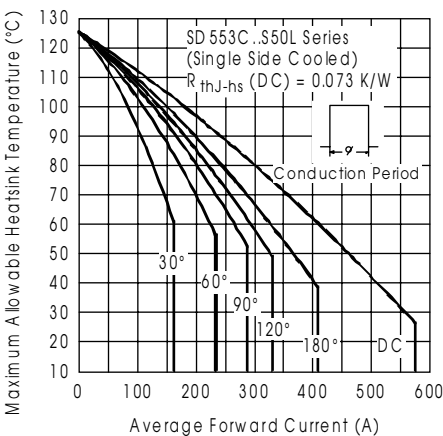


Fig. 2 - Current Ratings Characteristics

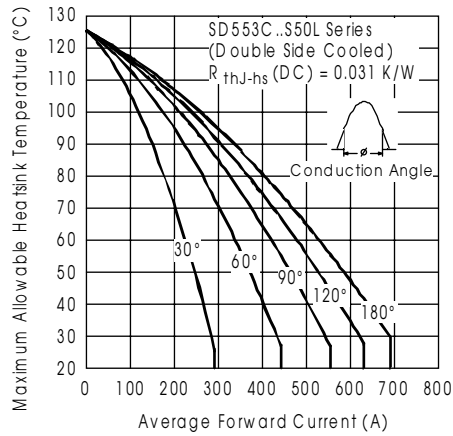


Fig. 3 - Current Ratings Characteristics

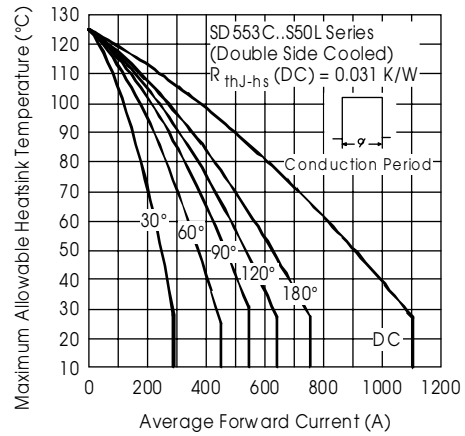


Fig. 4 - Current Ratings Characteristics

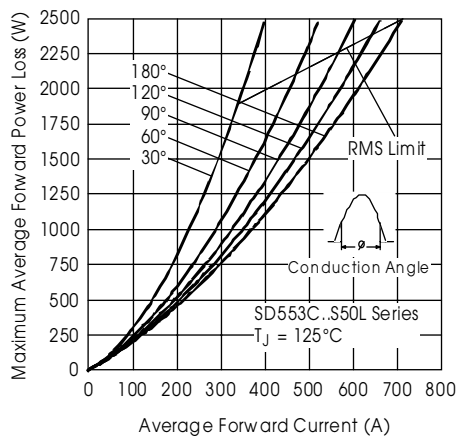


Fig. 5 - Forward Power Loss Characteristics

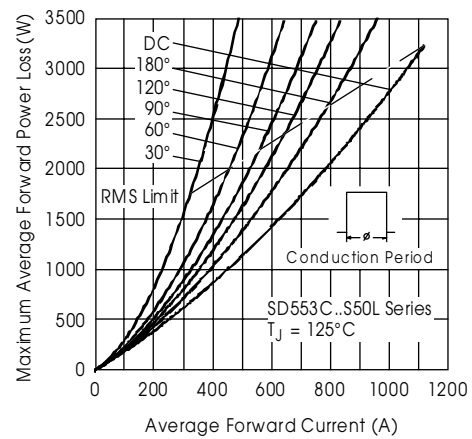


Fig. 6 - Forward Power Loss Characteristics

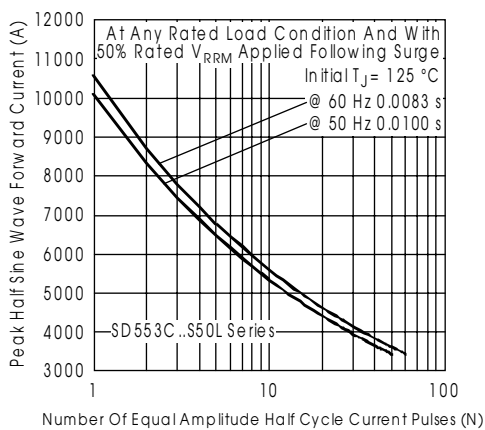


Fig. 7 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

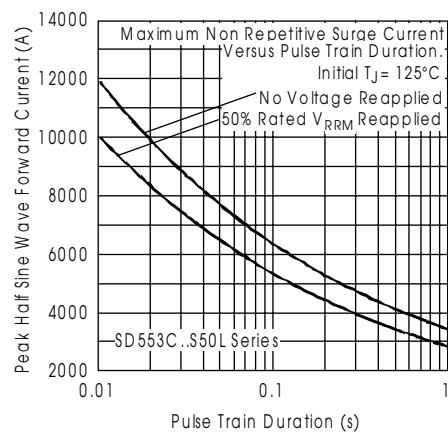


Fig. 8 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

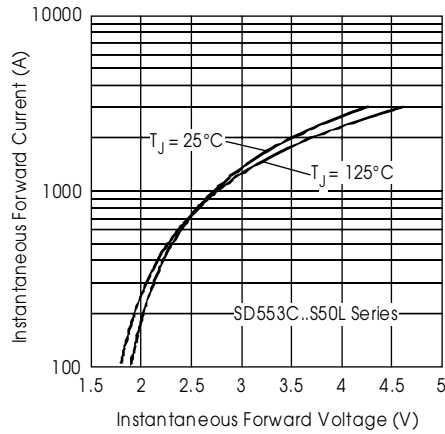


Fig. 9 - Forward Voltage Drop Characteristics

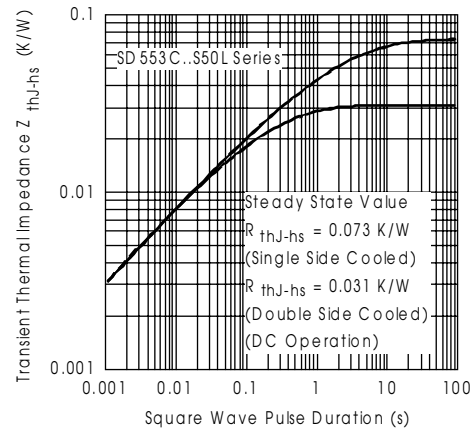
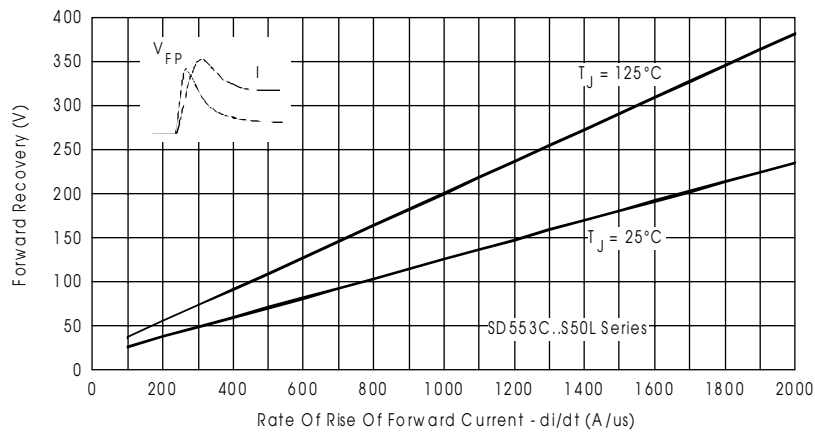
Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristic

Fig. 11 - Typical Forward Recovery Characteristics

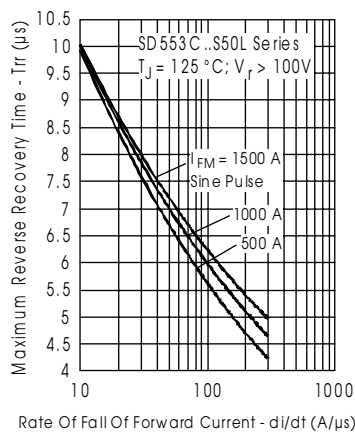


Fig. 12 - Recovery Time Characteristics

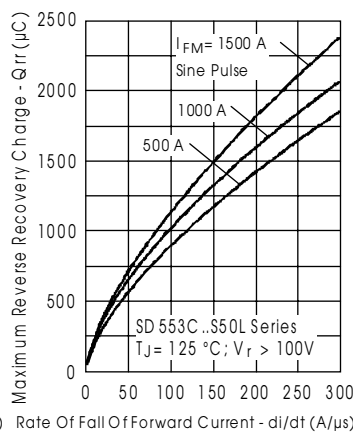


Fig. 13 - Recovery Charge Characteristics

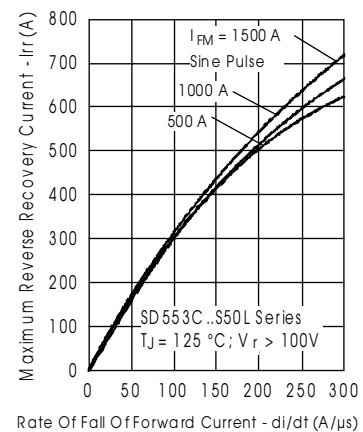


Fig. 14 - Recovery Current Characteristics

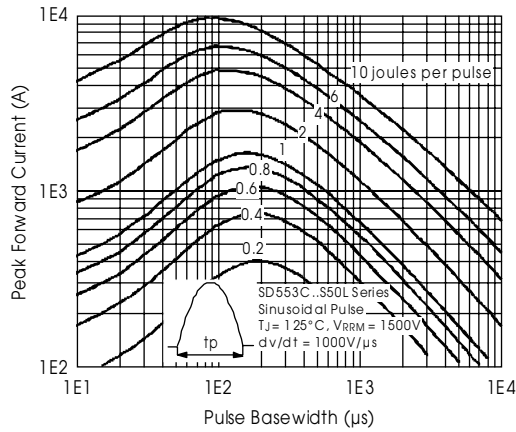


Fig. 15 - Maximum Total Energy Loss Per Pulse Characteristics

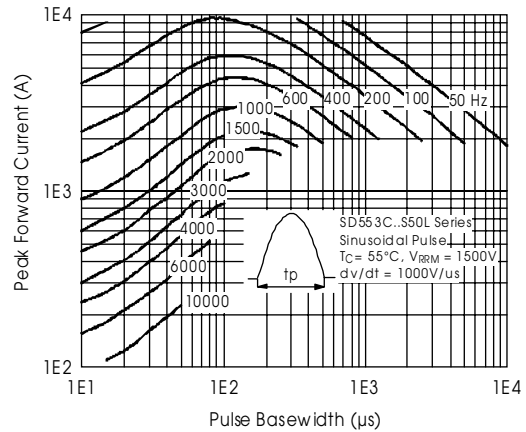


Fig. 16 - Frequency Characteristics

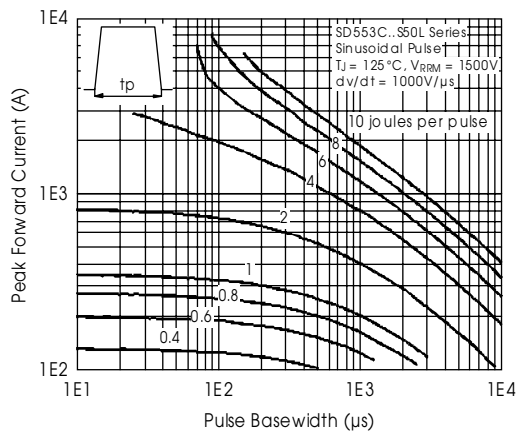


Fig. 17 - Maximum Total Energy Loss Per Pulse Characteristics

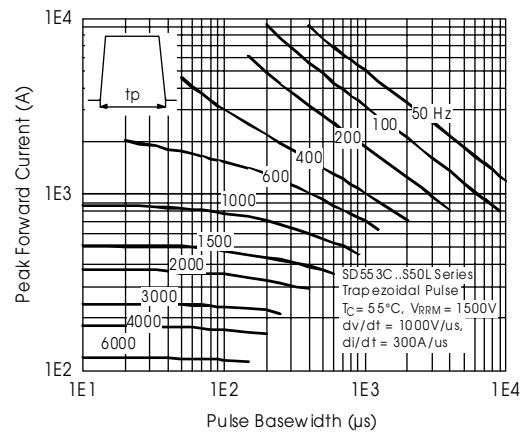


Fig. 18 - Frequency Characteristics

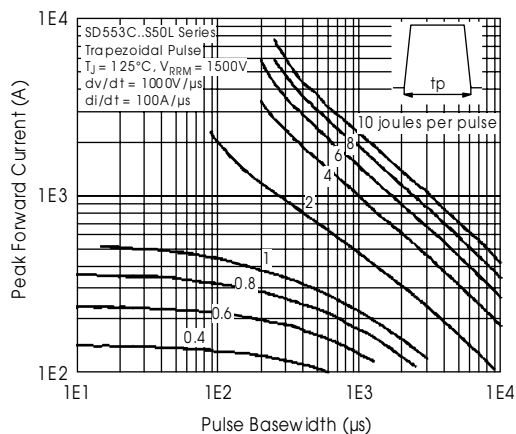


Fig. 19 - Maximum Total Energy Loss Per Pulse Characteristics

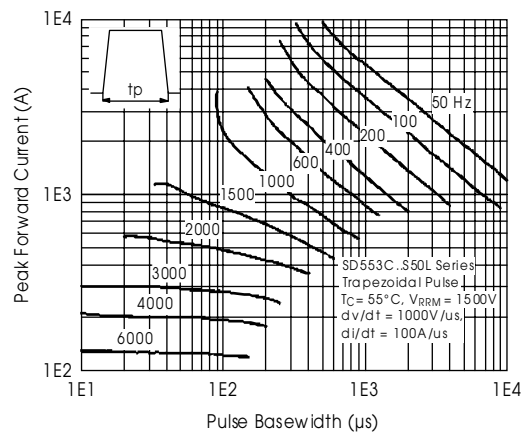


Fig. 20 - Frequency Characteristics